

# SG15A-SG15M

Fast Recovery Rectifiers

**VOLTAGE RANGE: 50 --- 1000 V**

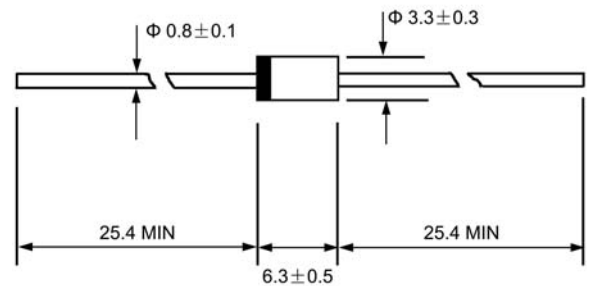
**CURRENT: 1.5 A**

**DO - 15**



## Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents



Dimensions in millimeters

## Mechanical Data

- ◇ Case: JEDEC DO-15, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 50 Hz, resistive or inductive load. For capacitive load, derate by 20%.

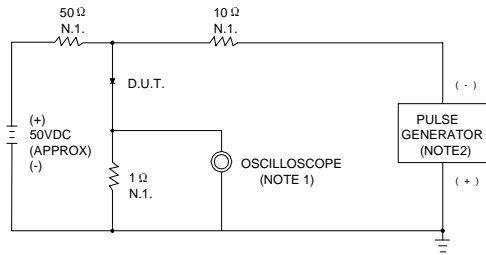
		SG 15A	SG 15B	SG 15D	SG 15G	SG 15J	SG 15K	SG 15M	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.5							A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	$I_{FSM}$	50.0							A
Maximum instantaneous forward voltage @ 1.5 A	$V_F$	1.3							V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$	5.0 100.0							$\mu\text{A}$
Maximum reverse recovery time (Note1)	$t_{rr}$	150			250	500		ns	
Typical junction capacitance (Note2)	$C_J$	18							pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	45							$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$	- 55 ---- + 150							$^\circ\text{C}$
Storage temperature range	$T_{STG}$	- 55 ---- + 150							$^\circ\text{C}$

NOTE: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .

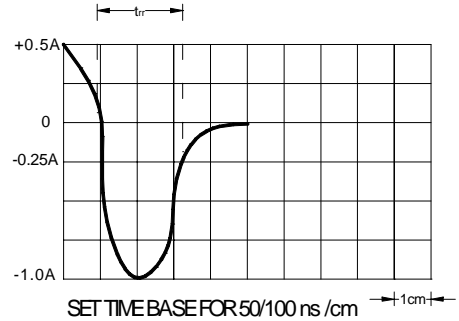
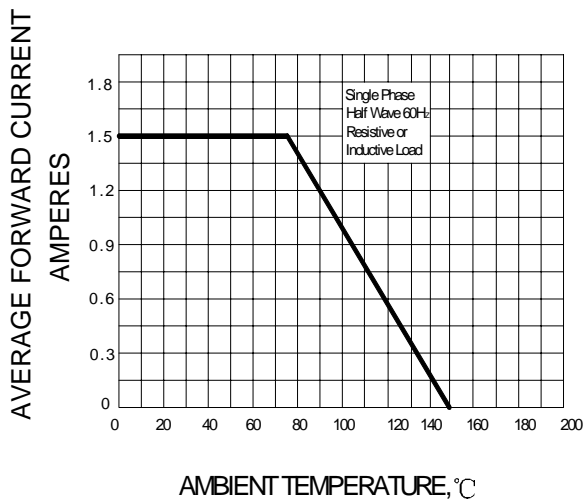
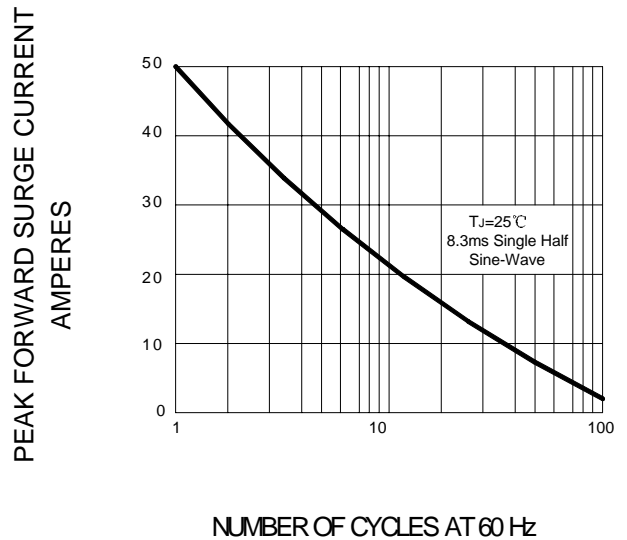
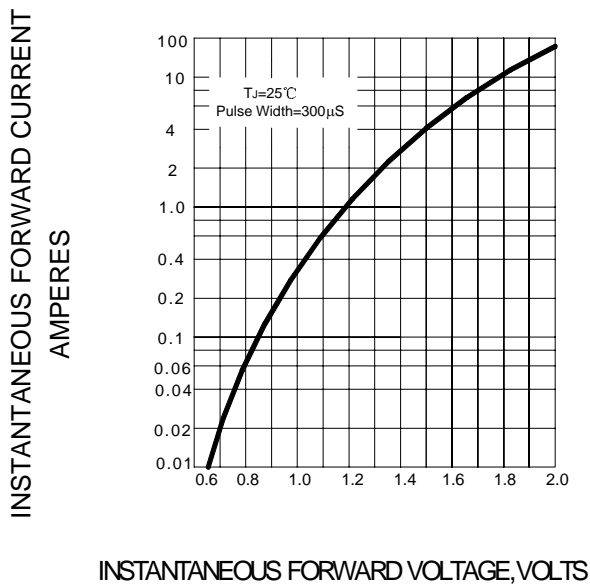
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient.

## Ratings AND Characteristic Curves

**FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**


NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF  
 2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω


**FIG.2 – FORWARD DERATING CURVE**

**FIG.3 – PEAK FORWARD SURGE CURRENT**

**FIG.4 – TYPICAL FORWARD CHARACTERISTIC**

**FIG.5 – TYPICAL JUNCTION CAPACITANCE**
